# **Z0103NN** Logic level four-quadrant triac Rev. 03 — 5 August 2009

**Product data sheet** 

#### **Product profile** 1.

#### 1.1 General description

Passivated sensitive gate 4-Q triac in a SOT223 surface-mountable plastic package

#### **1.2 Features and benefits**

- Direct interfacing to logic level ICs
- Direct interfacing to low power gate drive circuits

#### **1.3 Applications**

- General purpose low power motor control
- Home appliances

#### 1.4 Quick reference data

- High blocking voltage of 800V
- Sensitive gate in four quadrants
- Surface-mountable package
- Industrial process control
- Low power AC Fan controllers

Table 1.	Quick reference					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	-	800	V
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>sp</sub> ≤ 89 °C; see <u>Figure 1</u> and <u>4</u>	-	-	1	A
Static ch	aracteristics					
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; T2+ G-; see <u>Figure 6</u>	-	-	3	mA
		V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; T2- G-	-	-	3	mA
		V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; T2+ G+	-	-	3	mA
		V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; T2- G+	-	-	5	mA



### 2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1		
2	T2	main terminal 2		T2-T1
3	G	gate		`G sym051
4	T2	main terminal 2		
			SOT223 (SC-73)	

# 3. Ordering information

# Table 3. Ordering information Type number Package Name Description Version Z0103NN SC-73 plastic surface-mounted package with increased heatsink; 4 leads SOT223

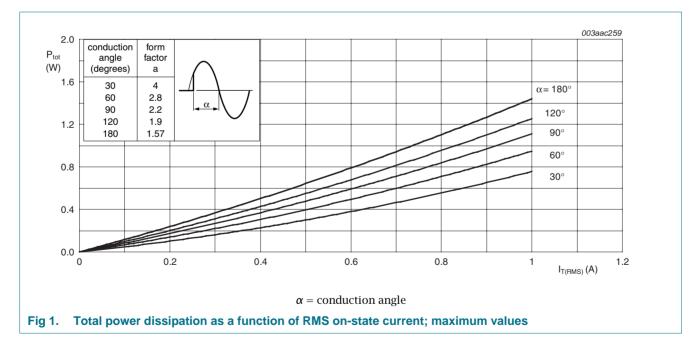
Logic level four-quadrant triac

#### 4. Limiting values

#### Table 4. Limiting values

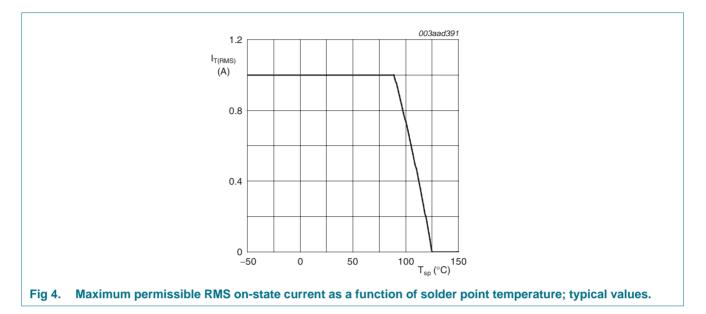
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		-	800	V
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; $T_{sp} \le 89 \text{ °C}$ ; see Figure 1 and 4	-	1	А
dl <sub>T</sub> /dt	rate of rise of on-state	$I_T$ = 1 A; $I_G$ = 20 mA; $dI_G/dt$ = 100 mA/µs; T2+ G-	-	50	A/µs
	current	$I_T$ = 1 A; $I_G$ = 20 mA; $dI_G/dt$ = 100 mA/µs; T2+ G+	-	50	A/µs
		$I_T$ = 1 A; $I_G$ = 20 mA; $dI_G/dt$ = 100 mA/µs; T2- G+	-	20	A/µs
		$I_{T}$ = 1 A; $I_{G}$ = 20 mA; $dI_{G}/dt$ = 100 mA/µs; T2- G-	-	50	A/µs
I <sub>GM</sub>	peak gate current		-	1	А
P <sub>GM</sub>	peak gate power		-	2	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C
I <sub>TSM</sub>	non-repetitive peak	full sine wave; t <sub>p</sub> = 16.7 ms; T <sub>j(init)</sub> = 25 °C	-	8.5	А
	on-state current	full sine wave; $t_p = 20$ ms; $T_{j(init)} = 25$ °C; see <u>Figure 2</u> and <u>3</u>	-	8	A
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sine-wave pulse	-	0.32	A <sup>2</sup> s
P <sub>G(AV)</sub>	average gate power		-	0.1	W



#### 003aad318 10 I<sub>TSM</sub> (A) 8 6 4 Ι<sub>Τ</sub> ITSM t 2 1/f T<sub>j(init)</sub> = 25 °C max 0 10 10<sup>2</sup> 10<sup>3</sup> 1 number of cycles f = 50 HzNon-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum Fig 2. values 003aad319 10<sup>3</sup> $\mathsf{I}_\mathsf{T}$ ITSM I<sub>TSM</sub> (A) t tp 10<sup>2</sup> T<sub>j(init)</sub> = 25 °C max (2) 10 1 10<sup>-5</sup> $10^{-4}$ 10<sup>-3</sup> 10<sup>-2</sup> $10^{-1}$ t<sub>p</sub> (s) $t_p \le 20 \text{ ms;} (1) \text{ is } dI_T/dt \text{ limit;}$ (2) is T2 - G + quadrant limitNon-repetitive peak on-state current as a function of pulse width; maximum values Fig 3.

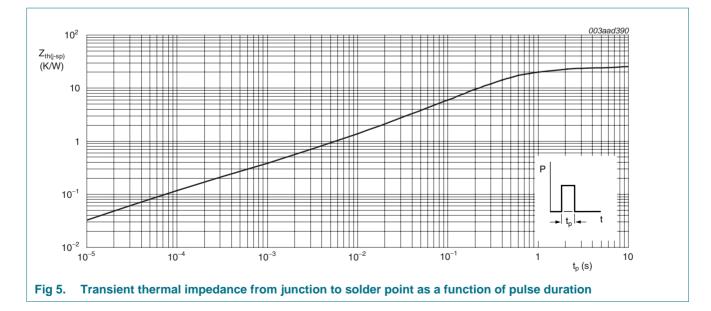
#### Logic level four-quadrant triac



### 5. Thermal characteristics

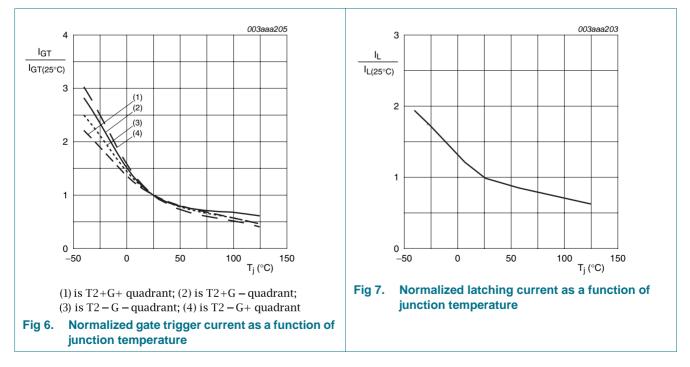
#### Table 5. Thermal characteristics

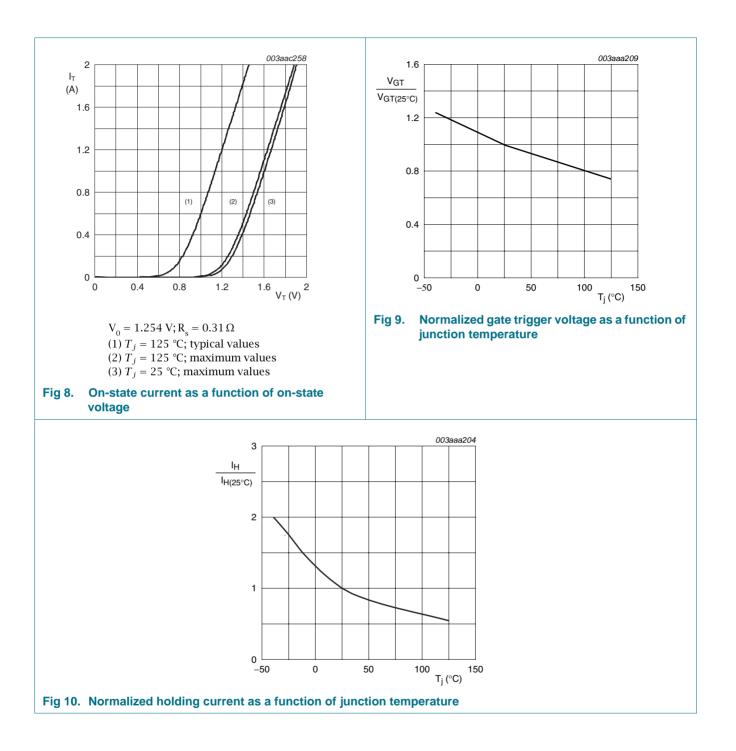
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	see <u>Figure 5</u>	-	-	25	K/W
R <sub>th(j-a)</sub>	thermal resistance from		-	150	-	K/W
	junction to ambient		-	60	-	K/W



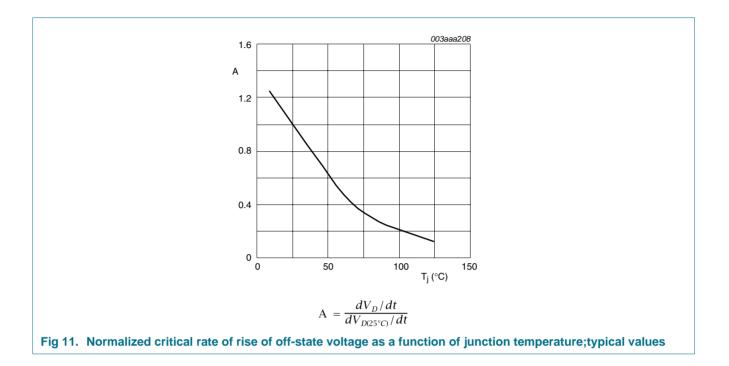
### 6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; T2+ G-; see <u>Figure 6</u>	-	-	3	mA
		V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; T2- G-	-	-	3	mA
		V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; T2+ G+	-	-	3	mA
		V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; T2- G+	-	-	5	mA
IL	latching current	$V_D = 12 \text{ V}; \text{ T}_j = 25 \text{ °C}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-};$ see <u>Figure 7</u>	-	-	15	mA
		$V_D = 12 \text{ V}; \text{ T}_j = 25 \text{ °C}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G+}$	-	-	7	mA
		$V_D = 12 \text{ V}; \text{ T}_j = 25 \text{ °C}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G+}$	-	-	7	mA
		$V_D = 12 \text{ V}; \text{ T}_j = 25 \text{ °C}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-}$	-	-	7	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; see <u>Figure 10</u>	-	-	7	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 1 A; see <u>Figure 8</u>	-	1.3	1.6	V
V <sub>GT</sub>	gate trigger voltage	I <sub>T</sub> = 0.1 A; V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; see <u>Figure 9</u>	-	-	1.3	V
		$I_T = 0.1 \text{ A}; V_D = 800 \text{ V}; T_j = 125 \text{ °C}$	0.2	-	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 800 V; T <sub>j</sub> = 125 °C	-	-	0.5	mA
Dynamic	characteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	V <sub>DM</sub> = 536 V; T <sub>j</sub> = 110 °C; gate open circuit; see <u>Figure 11</u>	10	-	-	V/µs
dV <sub>com</sub> /dt	rate of rise of commutating voltage	$V_D = 400 \text{ V}; \text{ T}_j = 110 \text{ °C};$ $dI_{com}/dt = 0.44 \text{ A/ms}; \text{ gate open circuit}$	0.5	-	-	V/µs





# Z0103NN Logic level four-quadrant triac



### 7. Package outline

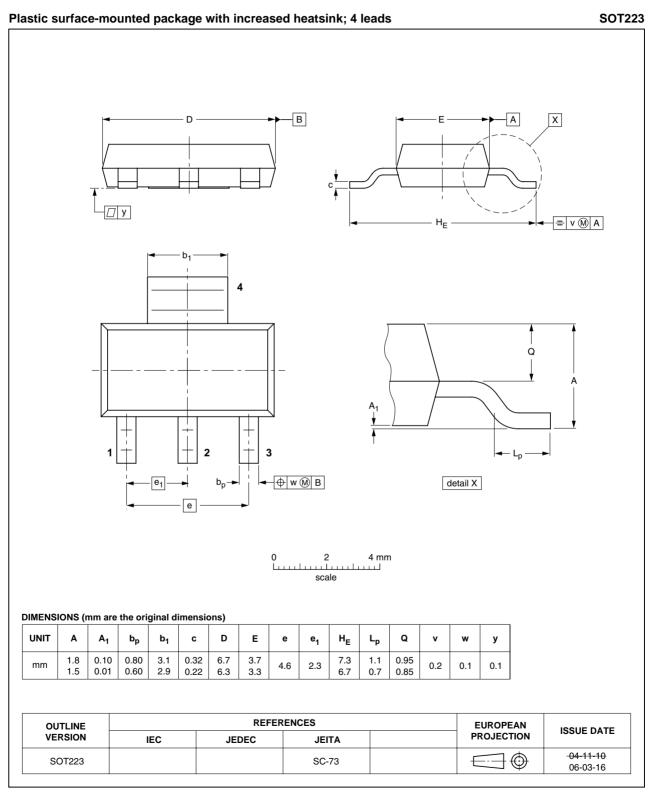


Fig 12. Package outline SOT223 (SC-73)

# 8. Revision history

Table 7.         Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
Z0103NN_3	20090805	Product data sheet	-	Z0103_07_09_SERIES-02
Modifications:		of this data sheet has beer of NXP Semiconductors.	redesigned to con	nply with the new identity
	<ul> <li>Legal texts</li> </ul>	have been adapted to the r	new company nam	e where appropriate.
	<ul> <li>Type number</li> </ul>	er Z0103NN separated fror	n data sheet Z0103	3_07_09_SERIES-02.
Z0103_07_09_SERIES-02 (9397 750 10102)	20020912	Product data	-	Z0103_07_09_SERIES-01
Z0103_07_09_SERIES-01 (9397 750 09419)	20020411	Product data	-	-

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Document status [1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions"

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Date of release: 5 August 2009 Document identifier: Z0103NN\_3

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